

/ Descriptions

TO-3P

Schottky Barrier Diode in a TO-3P Plastic Package.

/ Features

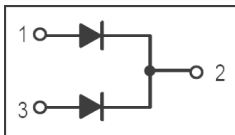
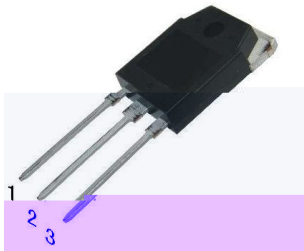
Low forward voltage drop, low power losses, High efficiency operation.

/ Applications

OR-ing

DC-DC

For use in high frequency inverters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

/ Equivalent Circuit**/ Pinning**

PIN1 Anode PIN 2 Cathode PIN 3 Anode

/ h_{FE} Classifications & Marking

See Marking Instructions.

Parameter	Symbol	Rating	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_{DC}	100	V
RMS Reverse Voltage	V_{RMS}	70	V
Average forward current	$I_{F(AV)}$	2×20	A
Non-Repetitive Peak Forward Surge Current	I_{FSM}	300	A
Thermal Resistance Junction to Ambient case	$R_{\theta Jc}$	2.8	/W
Operating and Storage Temperature Range	T_j T_{stg}	-40 +150	

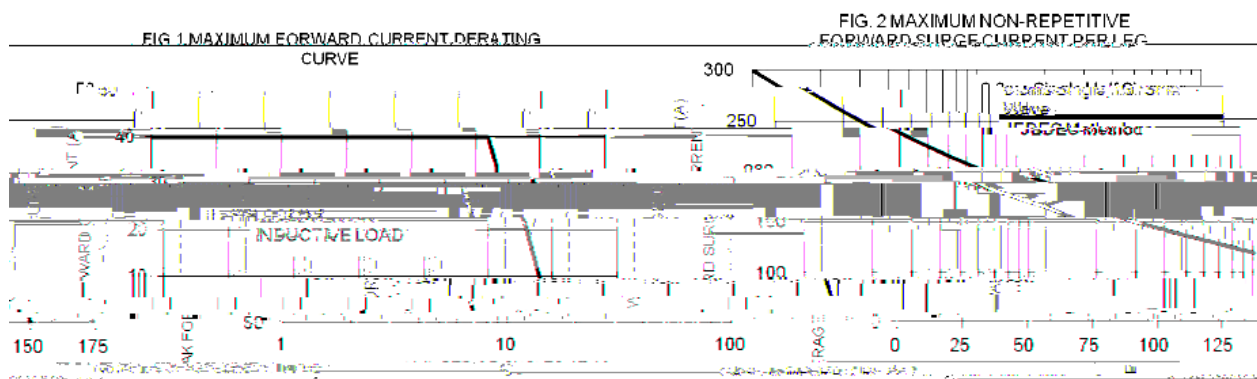
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Reverse Breakdown Voltage	V_{BR}	$I_R=1mA(T_a=25^\circ C)$	100			V

 I_F

Forward Voltage

 V_F

/ Electrical Characteristic Curve

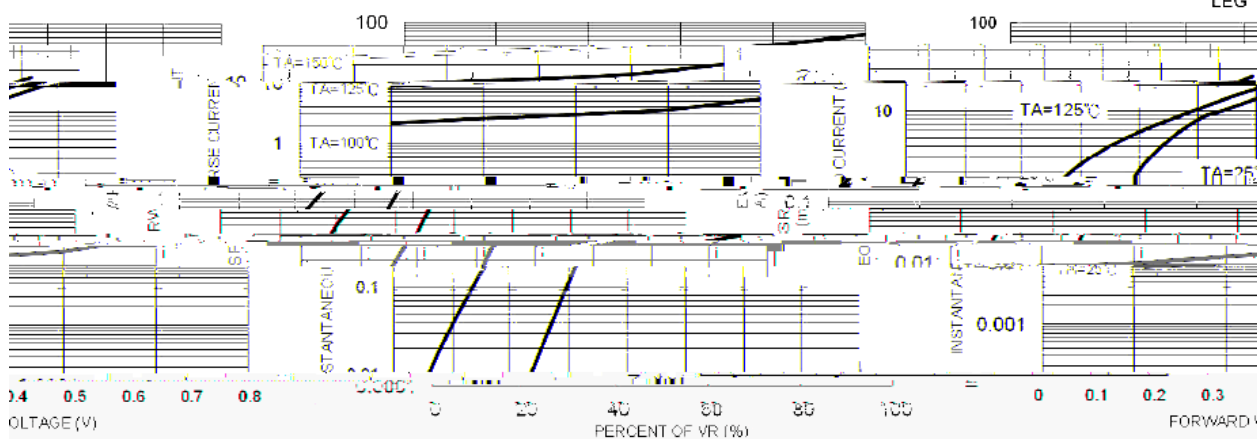


CHARACTERISTICS PER

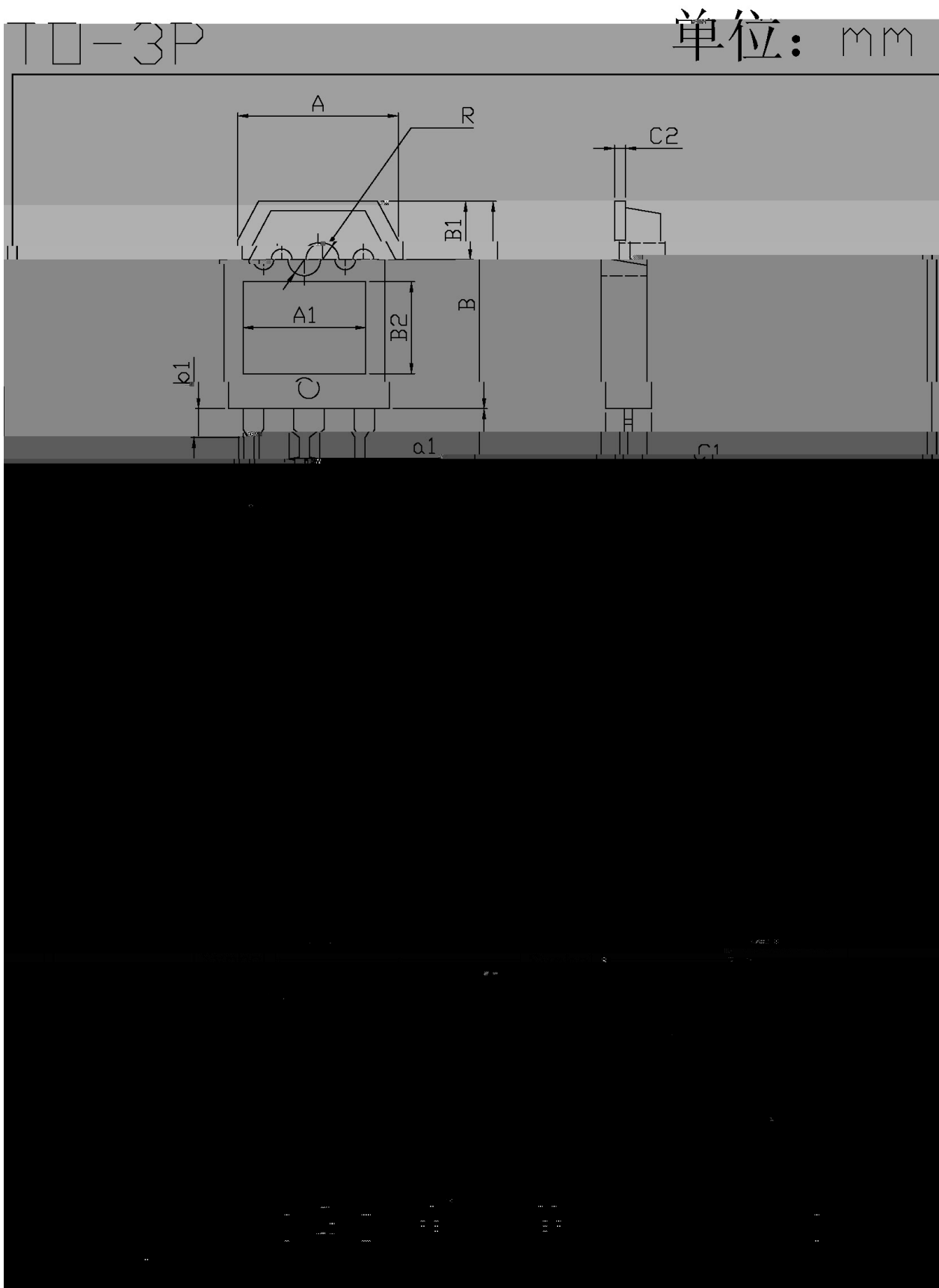
FIG. 4 TYPICAL REVERSE CHARACTERISTICS PER LEG

FIG. 3 TYPICAL FORWARD CH

LEG



/ Package Dimensions



/ Marking Instructions



BR

LV40100PT

Note:

BR: Company Code.

LV40100PT: Product Type.

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-------|-----|-----------|---|--------------------------------------|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 255±5 | | 5±0.5sec; | 2.Peak Temp.:255±5 , Duration:5±0.5sec. | |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

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